NSN 5962-01-518-4022

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View Online at https://aerobasegroup.com/nsn/5962-01-518-4022
Body Length:
0.740 inches
Body Width:
Between 0.460 inches and 0.520 inches
Body Height:
Between 0.045 inches and 0.115 inches
Maximum Power Dissipation Rating:
0.9 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Nha pn 0n651867-2 cage 98230, e/i kgv-61a
Features Provided:
Electrostatic sensitive and radiation hardened
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Cbbl
Current Rating Per Characteristic:
110.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Gold
Product Name:
Microcircuit, memory, digital, radiation-hardened, cmos/sos, 8k x 8 static ram, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds access
Memory Device Type:
Ram
Memory Capacity:
8kx8
Nuclear Hardness Critical Feature:
Hardened
Terminal Type And Quantity:

28 flat leads

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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